

## SWITCHING P-CHANNEL POWER MOSFET

### DESCRIPTION

The μ PA2731T1A is P-channel MOS Field Effect Transistor designed for power management applications of notebook computers and Li-ion battery protection circuit.

### FEATURES

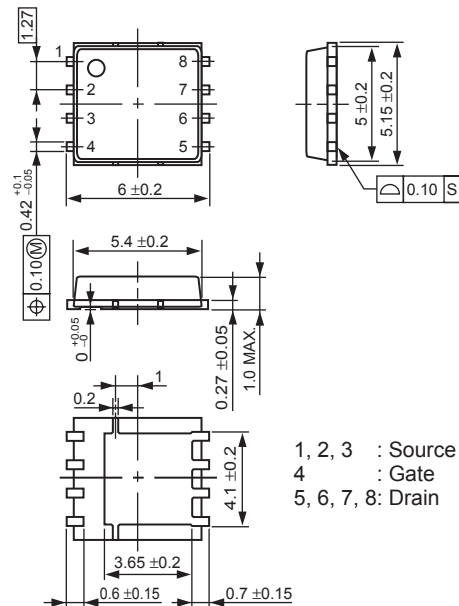
- Low on-state resistance  
 $R_{DS(on)1} = 3.3 \text{ m}\Omega \text{ MAX. (} V_{GS} = -10 \text{ V, } I_D = -22 \text{ A)}$   
 $R_{DS(on)2} = 6.4 \text{ m}\Omega \text{ MAX. (} V_{GS} = -4.5 \text{ V, } I_D = -22 \text{ A)}$
- Low  $C_{iss}$ :  $C_{iss} = 3620 \text{ pF TYP.}$
- Built-in gate protection diode
- Small and surface mount package (8pin HVSON)

### ORDERING INFORMATION

PART NUMBER	PACKAGE
μ PA2731T1A-E1-AZ <sup>Note</sup>	8pin HVSON
μ PA2731T1A-E2-AZ <sup>Note</sup>	8pin HVSON

**Note** Pb-free (This product does not contain Pb in external electrode.)

### PACKAGE DRAWING (Unit: mm)



### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C, All terminals are connected.)

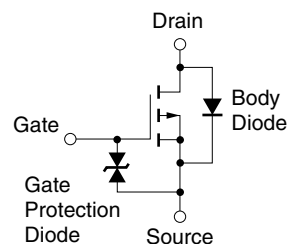
Drain to Source Voltage (V <sub>GS</sub> = 0 V)	V <sub>DSS</sub>	-30	V
Gate to Source Voltage (V <sub>DS</sub> = 0 V)	V <sub>GSS</sub>	±20	V
Drain Current (DC)	I <sub>D(DC)</sub>	±44	A
Drain Current (pulse) <sup>Note1</sup>	I <sub>D(pulse)</sub>	±180	A
Total Power Dissipation <sup>Note2</sup>	P <sub>T1</sub>	1.5	W
Total Power Dissipation (PW = 10 sec) <sup>Note2</sup>	P <sub>T2</sub>	4.6	W
Channel Temperature	T <sub>ch</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C
Single Avalanche Current <sup>Note3</sup>	I <sub>AS</sub>	-22	A
Single Avalanche Energy <sup>Note3</sup>	E <sub>AS</sub>	48	mJ

**Notes** 1. PW ≤ 10 μs, Duty Cycle ≤ 1%

2. Mounted on a glass epoxy board (25.4 mm x 25.4 mm x 0.8 mm)

3. Starting T<sub>ch</sub> = 25°C, V<sub>DD</sub> = -15 V, R<sub>G</sub> = 25 Ω, L = 100 μH, V<sub>GS</sub> = -20 → 0 V

### EQUIVALENT CIRCUIT



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

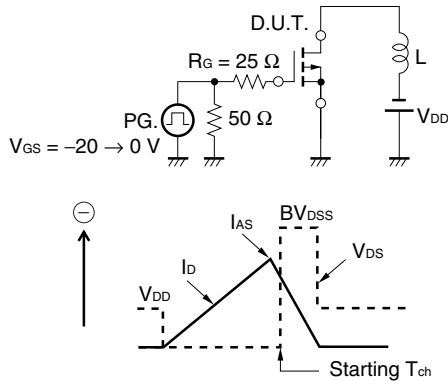
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**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C, All terminals are connected.)**

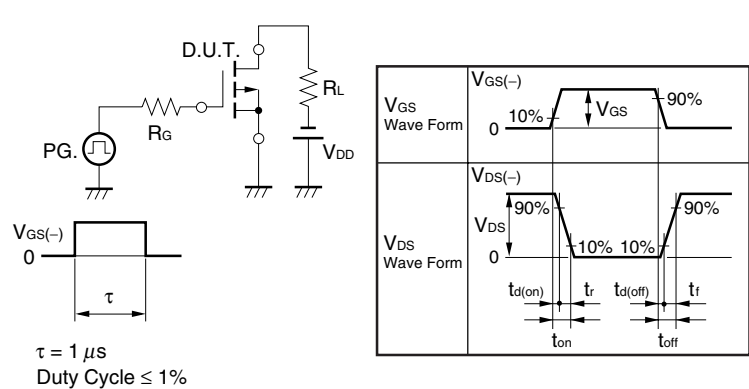
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = -30 V, V <sub>GS</sub> = 0 V			-1	μA
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V			±10	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1 mA	-1.0		-2.5	V
Drain to Source On-state Resistance <b>Note</b>	R <sub>DS(on)1</sub>	V <sub>GS</sub> = -10 V, I <sub>D</sub> = -22 A		2.6	3.3	mΩ
	R <sub>bS(on)2</sub>	V <sub>GS</sub> = -4.5 V, I <sub>D</sub> = -22 A		4.2	6.4	mΩ
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = -10 V		3620		pF
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V		1540		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1 MHz		630		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = -15 V, I <sub>D</sub> = -22 A		15		ns
Rise Time	t <sub>r</sub>	V <sub>GS</sub> = -10 V		16		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 10 Ω		760		ns
Fall Time	t <sub>f</sub>			510		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = -24 V		149		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = -10 V		17		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = -44 A		48		nC
Body Diode Forward Voltage <b>Note</b>	V <sub>F(S-D)</sub>	I <sub>F</sub> = 44 A, V <sub>GS</sub> = 0 V		0.85		V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 44 A, V <sub>GS</sub> = 0 V		87		ns
Reverse Recovery Charge	Q <sub>rr</sub>	di/dt = 50 A/μs		60		nC

**Note** Pulsed

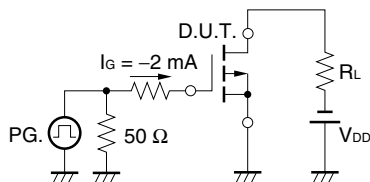
**TEST CIRCUIT 1 AVALANCHE CAPABILITY**



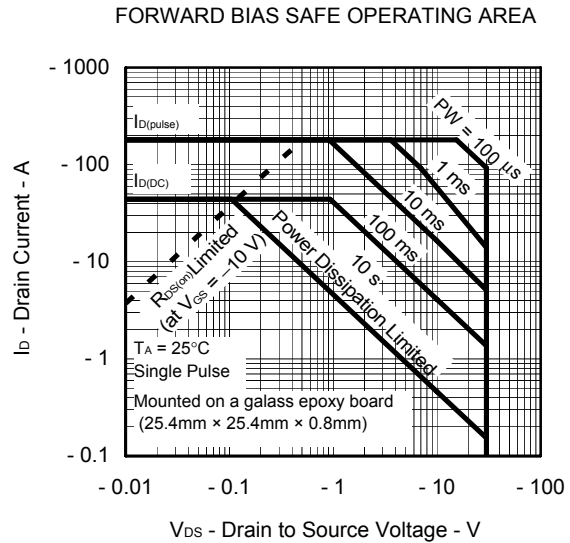
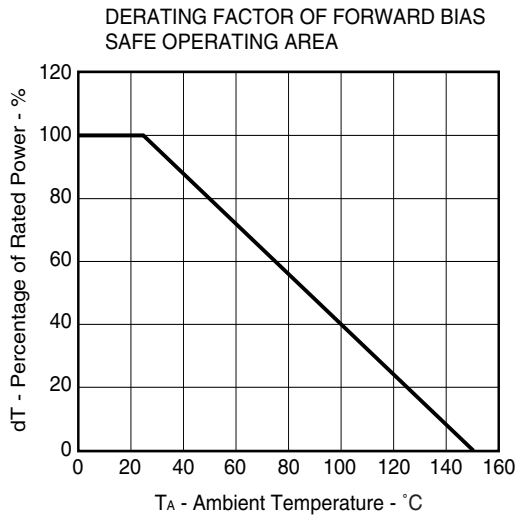
**TEST CIRCUIT 2 SWITCHING TIME**



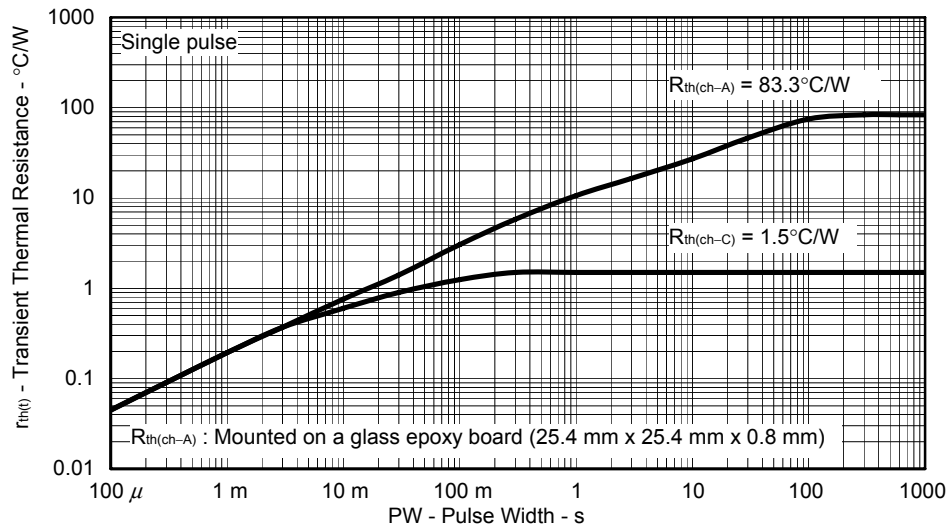
**TEST CIRCUIT 3 GATE CHARGE**



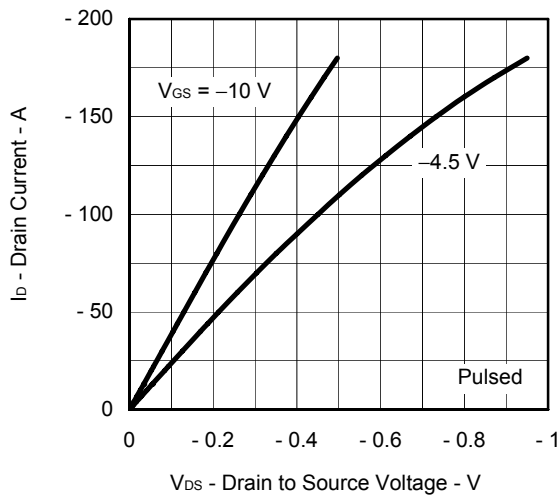
TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ )



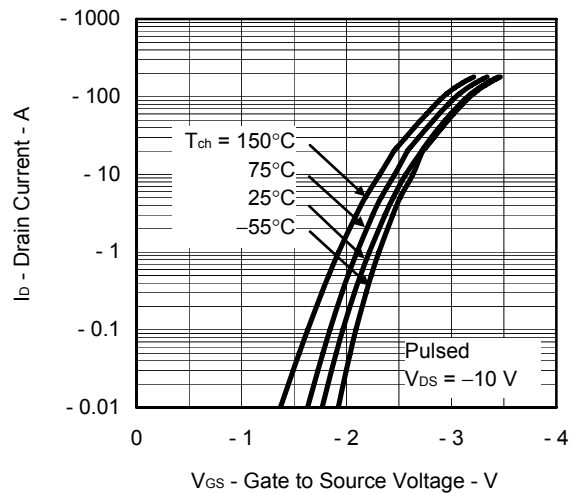
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



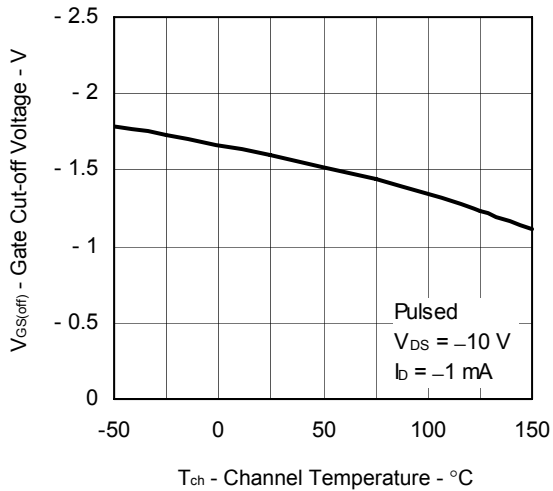
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



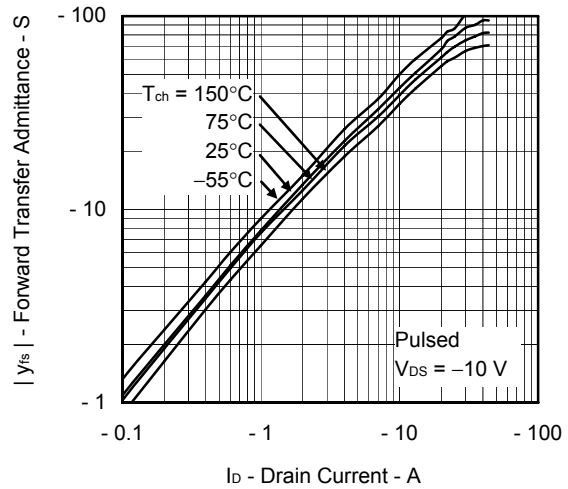
FORWARD TRANSFER CHARACTERISTICS



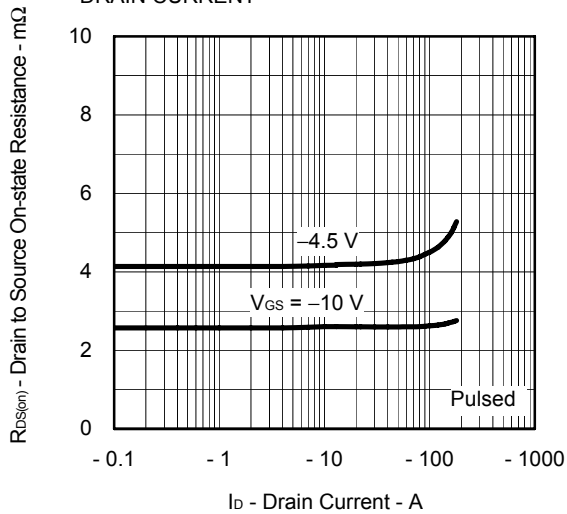
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



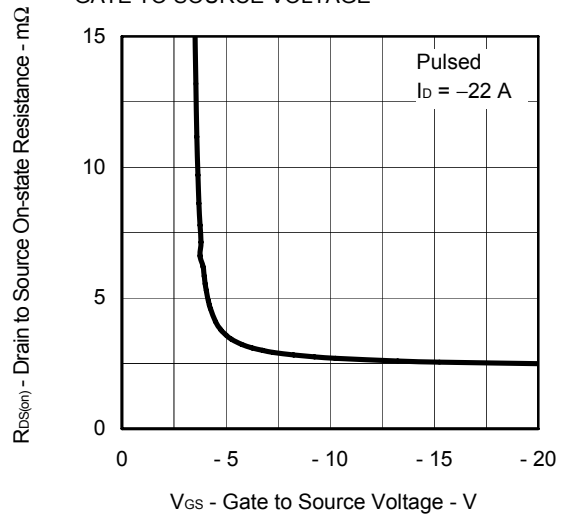
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



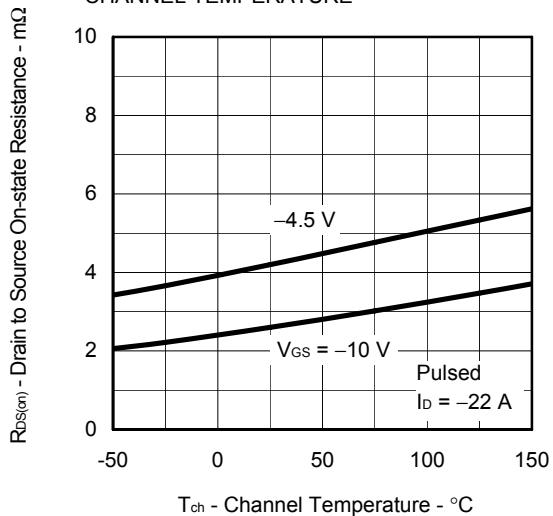
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



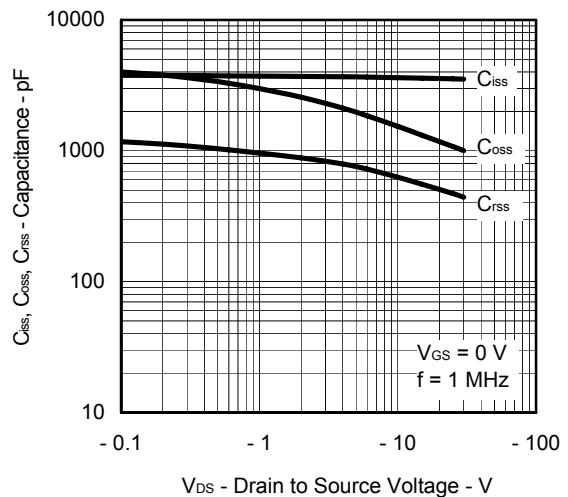
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



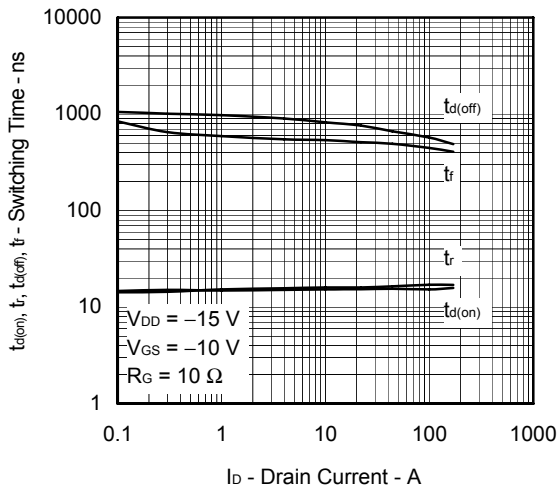
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



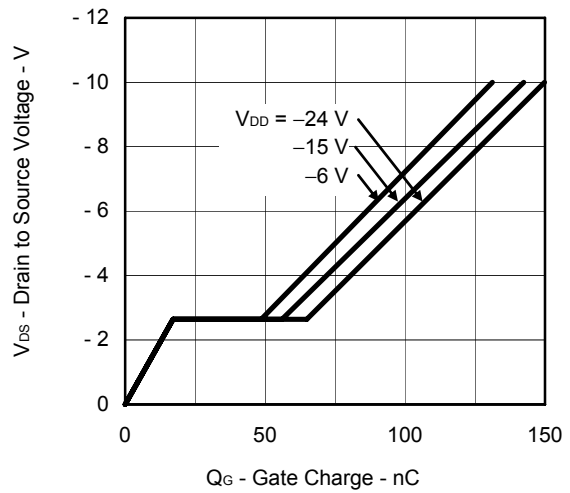
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



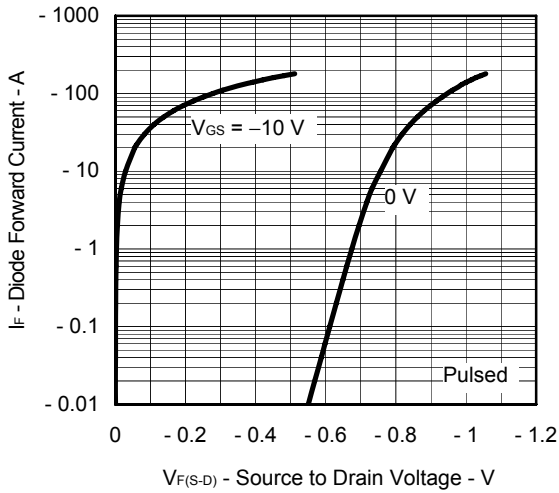
SWITCHING CHARACTERISTICS



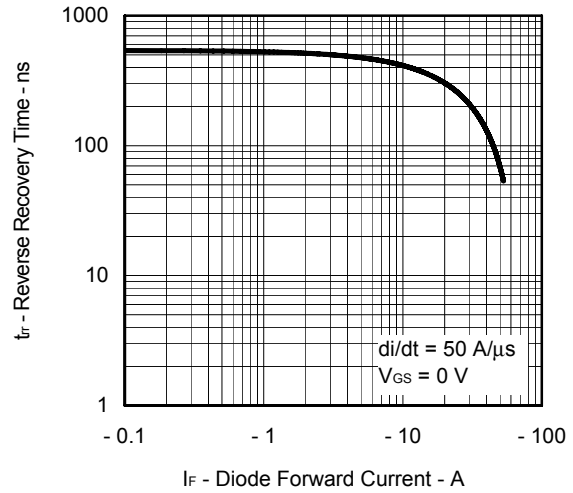
DYNAMIC INPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



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